

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2187	(shallow near5 junction)	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/10/13 12:51
L2	3352	(shallow and junction)	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/10/13 12:51
L3	3352	1 2	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/10/13 12:51
L4	16	3 and (heavy near5 (ion dopant))	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/10/13 12:52
L5	5646	(shallow near5 junction)	US-PGPU B; USPAT; USOCR	OR	ON	2005/10/13 12:53
L6	251	L5 and (heavy near5 (ion dopant))	US-PGPU B; USPAT; USOCR	OR	ON	2005/10/13 12:53
L7	210	L6 and (anneal\$3 heat\$3)	US-PGPU B; USPAT; USOCR	OR	ON	2005/10/13 12:53

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	229	(graded near10 silicon near10 germanium)	US-PGPU B; USPAT; USOCR	OR	ON	2005/10/13 14:37
L2	172	1 and concentration	US-PGPU B; USPAT; USOCR	OR	ON	2005/10/13 14:38
L3	106	(graded and silicon and germanium)	EPO; JPO; DERWENT ;	OR	ON	2005/10/13 14:37
L5	19	3 and concentration	EPO; JPO; DERWENT ;	OR	ON	2005/10/13 14:38